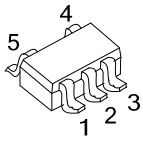
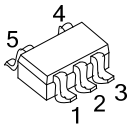
U74AUP1G07

CMOS IC

LOW-POWER BUFFER WITH OPEN-DRAIN OUTPUT



SOT-23-5
(JEDEC TO-236)



SOT-353

DFN-6(1.0×1.0)

■ DESCRIPTION

The **U74AUP1G07** provides the single non-inverting buffer with open-drain output. The output of the device is an open drain and can be connected to other open-drain outputs to implement active-LOW wire-OR active-HIGH wire-AND functions.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8V to 3.6V.

This device has power-down protective circuit, preventing device destruction when it is powered down.

■ FEATURES

* Wide supply voltage range from 0.8V to 3.6V
* Inputs accept voltages up to 3.6V
* I_{OFF} supports partial-power-down mode
* Low static power consumption; I_{CC}=0.5μA (Max.)
* Optimized for 3.3V Operation

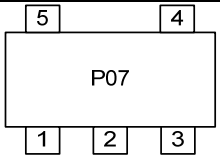
■ ORDERING INFORMATION

Ordering Number	Package	Packing
U74AUP1G07G-AE5-R	SOT-23-5	Tape Reel
U74AUP1G07G-AL5-R	SOT-353	Tape Reel
U74AUP1G07G-K06-1010-R	DFN-6(1.0×1.0)	Tape Reel

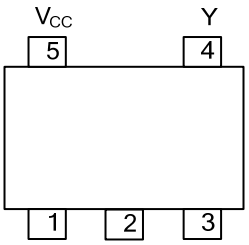
U74AUP1G07G-AE5-R
(1)Packing Type
(2)Package Type
(3)Green Package

(1) R: Tape Reel
(2) AE5: SOT-23-5, AL5: SOT-353,
K06-1010: DFN-6(1.0×1.0)
(3) G: Halogen Free and Lead Free

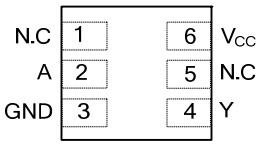
■ MARKING

SOT-23-5 / SOT-353	DFN-6(1.0×1.0)
	

■ PIN CONFIGURATION



SOT-23-5 / SOT-353



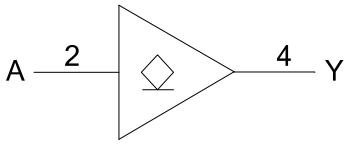
DFN-6(1.0×1.0)
(TOP VIEW)

■ FUNCTION TABLE (each gate)

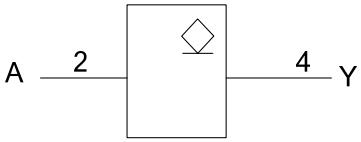
INPUT (A)	OUTPUT (Y)
L	L
H	Z

Note: H: HIGH voltage level; L: LOW voltage level; Z: high impedance state.

■ LOGIC DIAGRAM (positive logic)



Logic symbol



IEC logic symbol

■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	TEST CONDITIONS	RATINGS	UNIT
Supply Voltage	V_{CC}		-0.5 ~+4.6	V
Input Voltage	V_{IN}		-0.5 ~+4.6	V
Output Voltage	V_{OUT}	Output in the high or low state	-0.5 ~ V_{CC} +0.5	V
		Output in the power-off state	-0.5 ~ +4.6	V
Continuous V_{CC} or GND Current	I_{CC}		±50	mA
Continuous Output Current	I_{OUT}	V_{OUT}=0 ~ V_{CC}	±20	mA
Input Clamp Current	I_{IK}	V_{IN}<0	-50	mA
Output Clamp Current	I_{OK}	V_{OUT} >V_{CC} or V_{OUT}<0	-50	mA
Storage Temperature Range	T_{STG}		-65 ~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}	Operating	0.8		3.6	V
Input Voltage	V_{IN}		0		3.6	V
Output Voltage	V_{OUT}	High or low state	0		V_{CC}	V
Operating Temperature	T_A		-40		85	°C
Input Transition Rise or Fall Rate	Δt/Δv	V_{CC}=0.8V ~ 3.6V			200	ns/V

■ STATIC CHARACTERISTICS (T_A =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
HIGH-level Input Voltage	V_{IH}	V_{CC} =0.8V		0.7×V_{CC}			V
		V_{CC} =0.9V ~ 1.95V		0.65×V_{CC}			V
		V_{CC} =2.3V ~ 2.7V		1.6			V
		V_{CC} =3V ~ 3.6V		2.0			V
LOW-level Input Voltage	V_{IL}	V_{CC} =0.8V				0.3×V_{CC}	V
		V_{CC} =0.9V ~ 1.95V				0.35×V_{CC}	V
		V_{CC} =2.3V ~ 2.7V				0.7	V
		V_{CC} =3V to 3.6V				0.9	V
Low-Level Output Voltage	V_{OL}	V_{CC} =0.8V ~ 3.6V, I_{OH}=20μA				0.1	V
		V_{CC} =1.1V, I_{OH}=1.1mA				0.3×V_{CC}	V
		V_{CC} =1.4V, I_{OH}=1.7mA				0.31	V
		V_{CC} =1.65V, I_{OH}=1.9mA				0.31	V
		V_{CC} =2.3V	I_{OH}=2.3mA			0.31	V
			I_{OH}=3.1mA			0.44	V
		V_{CC} =3V	I_{OH}=2.7mA			0.31	V
			I_{OH}=4mA			0.44	V
Input Leakage Current	$I_{I(LEAK)}$	V_{CC} =0V ~ 3.6V, V_{IN}=V_{CC} or GND				±0.1	μA
OFF-State Output Current	I_{OZ}	V_{CC}=0V ~3.6V, V_{IN}=V_{IH}, V_O=0V~3.6V				±0.1	μA
Power OFF Leakage Current	I_{OFF}	V_{CC} =0V, V_{IN} or V_O=0V~3.6V				±0.2	μA
Additional Power-off Leakage Current	ΔI_{OFF}	V_{CC}=0V~0.2V, V_{IN} or V_O=0V~3.6V				±0.2	μA
Quiescent Supply Current	I_{CC}	V_{CC} =0.8V ~3.6V, V_{IN}=V_{CC} or GND I_{OUT}=0				0.5	μA
Additional Quiescent Supply Current	ΔI_{CC}	V_{CC} =3.3V, One input at V_{CC}-0.6V, Other inputs at V_{CC} or GND				40	μA
nput Capacitance	C_I	$_{CC}$=0V, V_{IN}=V_{CC} or GND			1.5		pF
		$_{CC}$=3.6V, V_{IN}=V_{CC} or GND			1.7		pF
utput Capacitance	C_{OUT}	$_{CC}$ =0V, V_{OUT}=GND			1.7		pF

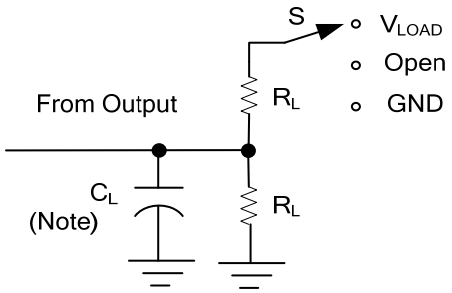
■ DYNAMIC CHARACTERISTICS (T_A =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Propagation delay from input (A) to output(Y)	t_{PD}	C_L=5pF, R_L=5KΩ	V_{CC}=0.8V		12.2		ns
			V_{CC}=1.2V±0.1V	2.1	5.1		ns
			V_{CC}=1.5V±0.1V	1.6	3.6		ns
			V_{CC}=1.8V±0.15V	1.6	3.1		ns
			V_{CC}=2.5V±0.2V	1.1	2.1		ns
			V_{CC}=3.3V±0.3V	1.4	2.2		ns
		C_L=10pF, R_L=5KΩ	V_{CC}=0.8V		15		ns
			V_{CC}=1.2V±0.1V	3	6.2		ns
			V_{CC}=1.5V±0.1V	2.3	4.4		ns
			V_{CC}=1.8V±0.15V	2.4	3.9		ns
			V_{CC}=2.5V±0.2V	1.7	2.8		ns
			V_{CC}=3.3V±0.3V	2.2	3.0		ns
		C_L=15pF, R_L=5KΩ	V_{CC}=0.8V		18.2		ns
			V_{CC}=1.2V±0.1V	3.5	7.3		ns
			V_{CC}=1.5V±0.1V	3	5.2		ns
			V_{CC}=1.8V±0.15V	2.8	4.8		ns
			V_{CC}=2.5V±0.2V	2.4	3.4		ns
			V_{CC}=3.3V±0.3V	2.2	3.7		ns
		C_L=30pF, R_L=5KΩ	V_{CC}=0.8V		26.5		ns
			V_{CC}=1.2V±0.1V	4.8	10.7		ns
			V_{CC}=1.5V±0.1V	4.1	7.7		ns
			V_{CC}=1.8V±0.15V	3.8	7.5		ns
			V_{CC}=2.5V±0.2V	3.7	5.4		ns
			V_{CC}=3.3V±0.3V	3.6	6.3		ns

■ OPERATING CHARACTERISTICS (f =1 MHz; V_I=V_{CC} or GND, T_A =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDTIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C_{PD}	V_{CC}=0.8V		1.0		pF
		V_{CC}=1.2V±0.1V		1.0		pF
		V_{CC}=1.5V±0.1V		1.0		pF
		V_{CC}=1.8V±0.15V		1.0		pF
		V_{CC}=2.5V±0.2V		1.0		pF
		V_{CC}=3.3V±0.3V		1.0		pF

■ TEST CIRCUIT AND WAVEFORMS



TEST	S
t_{PZL} (Note 1)	V_{LOAD}
t_{PLZ} (Note 1)	V_{LOAD}

Note: Since this device has open drain outputs, the t_{PLZ} and t_{PZL} is the same as t_{PLH} and t_{PHL}.

V_{CC}	V_{IN}	t_R / t_F	V_M	V_{LOAD}	C_L	R_L	V_Δ
0.8	V_{CC}	3ns	$V_{CC}/2$	$2\times V_{CC}$	5,10,15,30pF	5kΩ	0.1V
1.2±0.1V	V_{CC}	3ns	$V_{CC}/2$	$2\times V_{CC}$	5,10,15,30pF	5kΩ	0.1V
1.5±0.1V	V_{CC}	3ns	$V_{CC}/2$	$2\times V_{CC}$	5,10,15,30pF	5kΩ	0.1V
1.8±0.15V	V_{CC}	3ns	$V_{CC}/2$	$2\times V_{CC}$	5,10,15,30pF	5kΩ	0.15V
2.5±0.2V	V_{CC}	3ns	$V_{CC}/2$	$2\times V_{CC}$	5,10,15,30pF	5kΩ	0.15V
3.3±0.3V	V_{CC}	3ns	$V_{CC}/2$	$2\times V_{CC}$	5,10,15,30pF	5kΩ	0.3V